

# Ananth Dodabalapur

## List of Publications by Year in descending order

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92  
papers

3,474  
citations

147801

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138484

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92  
docs citations

92  
times ranked

5281  
citing authors

#	ARTICLE	IF	CITATIONS
1	Nanospike electrodes and charge nanoribbons: A new design for nanoscale thin-film transistors. Science Advances, 2022, 8, eabm1154.	10.3	10
2	Wafer-Scalable Single-Layer Amorphous Molybdenum Trioxide. ACS Nano, 2022, 16, 3756-3767.	14.6	16
3	Analog Circuits Using Double-Gate Multilayer MoS <sub>2</sub> Field-Effect Transistor for Sensor Applications. IEEE Transactions on Electron Devices, 2022, 69, 3470-3476.	3.0	1
4	Charge Focusing and Enhanced Fermi-Level Modulation in Hybrid Graphene Nanospike Organic Thin-Film Transistors. ACS Applied Nano Materials, 2022, 5, 8710-8716.	5.0	0
5	Carrier Velocity in Amorphous Metal-Oxide Semiconductor Transistors. IEEE Transactions on Electron Devices, 2021, 68, 125-131.	3.0	10
6	Phenomenological Model of Gate-Dependent Kink in I-V Characteristics of MoS <sub>2</sub> Double-Gate FETs. IEEE Journal of the Electron Devices Society, 2021, 9, 441-446.	2.1	1
7	Reflecting metagrating-enhanced thin-film organic light emitting devices. Applied Physics Letters, 2021, 118, .	3.3	5
8	Field-Emission Enhanced Contacts for Disordered Semiconductor based Thin-Film Transistors. , 2021, , .		1
9	Interface roughness and interface roughness scattering in amorphous oxide thin-film transistors. Journal of Applied Physics, 2021, 130, .	2.5	7
10	Modeling of a tunable memory device made with a double-gate MoS <sub>2</sub> FET and graphene floating gate. Applied Physics Letters, 2021, 119, 143506.	3.3	0
11	Nanospike Electrode Designs for Improved Electrical Performance in Nanoscale Organic Thin-Film Transistors. ACS Applied Electronic Materials, 2021, 3, 4284-4290.	4.3	9
12	A Sawtooth Relaxation ICO based 1-1 MASH ADC. , 2020, , .		2
13	Level-Crossing Detection based Low-Power Sigma-Delta ADC for Sensor Applications. , 2020, , .		3
14	Double-Gate MoS <sub>2</sub> Field-Effect Transistor with a Multilayer Graphene Floating Gate: A Versatile Device for Logic, Memory, and Synaptic Applications. ACS Applied Materials & Interfaces, 2020, 12, 33926-33933.	8.0	41
15	Going beyond polaronic theories in describing charge transport in rubrene single crystals. Applied Physics Letters, 2020, 116, 093301.	3.3	5
16	Charge transport and dynamic response of organic and polymer transistors. Journal of Applied Physics, 2020, 127, 105501.	2.5	5
17	Symmetry of Gating in Double-Gate MoS <sub>2</sub> FETs. IEEE Transactions on Electron Devices, 2019, 66, 4468-4473.	3.0	9
18	Analysis of the Advantages of Nanostripe-Channel Geometries for Thin-Film Transistors. IEEE Transactions on Electron Devices, 2019, 66, 2606-2613.	3.0	3

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19	Redefining the Mobility Edge in Thin-Film Transistors. <i>Physical Review Applied</i> , 2019, 11, .	3.8	16
20	Enhanced Hole Injection Into Single Layer WSe <sub>2</sub> . <i>IEEE Journal of the Electron Devices Society</i> , 2018, 6, 309-313.	2.1	2
21	Enhanced Photoresponse in Metasurface-Integrated Organic Photodetectors. <i>Nano Letters</i> , 2018, 18, 3362-3367.	9.1	25
22	Trapped Carrier Scattering and Charge Transport in High-Mobility Amorphous Metal Oxide Thin-Film Transistors. <i>Annalen Der Physik</i> , 2018, 530, 1800341.	2.4	17
23	Inkjet-Printed Lithium-Sulfur Microcathodes for All-Printed, Integrated Nanomanufacturing. <i>Small</i> , 2017, 13, 1603786.	10.0	62
24	Polarization effects from the ambient and the gate dielectric on charge transport in polymer field-effect transistors. <i>Applied Physics Letters</i> , 2017, 110, 243302.	3.3	6
25	Modeling of a Back-Gated Monolayer MoS <sub>2</sub> FET by Extraction of an Accurate Threshold Voltage and Gate-Bias-Dependent Source/Drain Resistance. <i>IEEE Journal of the Electron Devices Society</i> , 2017, 5, 384-389.	2.1	8
26	Electrical performance enhancement of 20 nm scale graphene nanoribbon field-effect transistors with dipolar molecules. , 2016, , .		0
27	Inkjet printed carbon nanotubes in short channel field effect transistors: influence of nanotube distortion and gate insulator interface modification. <i>Flexible and Printed Electronics</i> , 2016, 1, 035001.	2.7	5
28	Charge Transport in Deep and Shallow States in a High-Mobility Polymer FET. <i>IEEE Transactions on Electron Devices</i> , 2016, 63, 1254-1259.	3.0	10
29	57.4:Invited Paper: Device Physics of Amorphous Oxide Thin-Film Transistors. <i>Digest of Technical Papers SID International Symposium</i> , 2015, 46, 861-864.	0.3	1
30	Short Channel Field-Effect-Transistors with Inkjet-Printed Semiconducting Carbon Nanotubes. <i>Small</i> , 2015, 11, 5505-5509.	10.0	16
31	Using lateral bulk heterojunctions to study the effects of additives on PTB7:PC61BM space charge regions. <i>Synthetic Metals</i> , 2015, 209, 158-163.	3.9	2
32	Toward air-stable multilayer phosphorene thin-films and transistors. <i>Scientific Reports</i> , 2015, 5, 8989.	3.3	344
33	Fluoropolymer coatings for improved carbon nanotube transistor device and circuit performance. <i>Applied Physics Letters</i> , 2014, 105, 122107.	3.3	26
34	Density of trap states in a polymer field-effect transistor. <i>Applied Physics Letters</i> , 2014, 105, .	3.3	10
35	A Study of Diphenylfumaronitrile and Furan-Substituted Diketopyrrolopyrrole Alternating Copolymer and Its Thin-Film Transistors. <i>Macromolecular Chemistry and Physics</i> , 2014, 215, 725-732.	2.2	14
36	Use of lateral structures to monitor and evaluate degradation of key photovoltaic parameters in an organic bulk heterojunction material. <i>Journal of Applied Physics</i> , 2014, 116, .	2.5	1

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37	Synthesis of diketopyrrolopyrrole based copolymers via the direct arylation method for p-channel and ambipolar OFETs. <i>Physical Chemistry Chemical Physics</i> , 2014, 16, 4275.	2.8	43
38	High-Speed, Inkjet-Printed Carbon Nanotube/Zinc Tin Oxide Hybrid Complementary Ring Oscillators. <i>Nano Letters</i> , 2014, 14, 3683-3687.	9.1	133
39	Improved Performance in Diketopyrrolopyrrole-Based Transistors with Bilayer Gate Dielectrics. <i>ACS Applied Materials &amp; Interfaces</i> , 2014, 6, 3170-3175.	8.0	33
40	Evaluating Charge Carrier Mobility Balance in Organic Bulk Heterojunctions using Lateral Device Structures. <i>Journal of Physical Chemistry C</i> , 2014, 118, 18299-18306.	3.1	6
41	Effects of contact resistance on the evaluation of charge carrier mobilities and transport parameters in amorphous zinc tin oxide thin-film transistors. <i>Applied Physics A: Materials Science and Processing</i> , 2014, 115, 1103-1107.	2.3	7
42	Analysis of bulk heterojunction material parameters using lateral device structures. <i>Journal of Photonics for Energy</i> , 2014, 4, 040994.	1.3	4
43	Logic-Gate Devices Based on Printed Polymer Semiconducting Nanostripes. <i>Nano Letters</i> , 2013, 13, 3643-3647.	9.1	44
44	Synthesis, characterization and organic field effect transistor performance of a diketopyrrolopyrrole-fluorenone copolymer. <i>Physical Chemistry Chemical Physics</i> , 2013, 15, 7475.	2.8	8
45	Quantifying space charge accumulation in organic bulk heterojunctions by nonlinear optical microscopy. <i>Organic Electronics</i> , 2013, 14, 3014-3018.	2.6	4
46	Charge transport study of high mobility polymer thin-film transistors based on thiophene substituted diketopyrrolopyrrole copolymers. <i>Physical Chemistry Chemical Physics</i> , 2013, 15, 9735.	2.8	43
47	A fluorenone based low band gap solution processable copolymer for air stable and high mobility organic field effect transistors. <i>Chemical Communications</i> , 2013, 49, 1588-1590.	4.1	41
48	High-Performance Current Saturating Graphene Field-Effect Transistor With Hexagonal Boron Nitride Dielectric on Flexible Polymeric Substrates. <i>IEEE Electron Device Letters</i> , 2013, 34, 172-174.	3.9	53
49	Isosindigo dye incorporated copolymers with naphthalene and anthracene: promising materials for stable organic field effect transistors. <i>Polymer Chemistry</i> , 2013, 4, 1983.	3.9	44
50	Low voltage, high performance inkjet printed carbon nanotube transistors with solution processed ZrO <sub>2</sub> gate insulator. <i>Applied Physics Letters</i> , 2013, 103, .	3.3	44
51	Effect of film nanostructure on in-plane charge transport in organic bulk heterojunction materials. , 2013, , .		0
52	Mapping electric field distributions in biased organic bulk heterojunctions under illumination by nonlinear optical microscopy. <i>Applied Physics Letters</i> , 2013, 102, .	3.3	20
53	Bimolecular recombination coefficient calculation by <i>in situ</i> potentiometry in a bulk heterojunction organic photovoltaic material. <i>Applied Physics Letters</i> , 2013, 102, 173304.	3.3	5
54	Investigation of the physics of sensing in organic field effect transistor based sensors. <i>Journal of Applied Physics</i> , 2012, 111, 044509.	2.5	42

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55	Charge-Carrier Velocity Distributions in High-Mobility Polymer Dual-Gate Thin-Film Transistors. IEEE Electron Device Letters, 2012, 33, 899-901.	3.9	8
56	Furan substituted diketopyrrolopyrrole and thienylenevinylene based low band gap copolymer for high mobility organic thin film transistors. Journal of Materials Chemistry, 2012, 22, 17284.	6.7	52
57	State-of-the-art graphene transistors on hexagonal boron nitride, high-k, and polymeric films for GHz flexible analog nanoelectronics. , 2012, , .		7
58	Scanning photocurrent microscopy of lateral organic bulk heterojunctions. Physical Chemistry Chemical Physics, 2012, 14, 13199.	2.8	21
59	ZnO layers for opto-electronic applications from solution-based and low-temperature processing of an organometallic precursor. Journal of Materials Chemistry, 2012, 22, 20896.	6.7	18
60	A furan-containing conjugated polymer for high mobility ambipolar organic thin film transistors. Chemical Communications, 2012, 48, 8383.	4.1	88
61	Furan containing diketopyrrolopyrrole copolymers: synthesis, characterization, organic field effect transistor performance and photovoltaic properties. Journal of Materials Chemistry, 2012, 22, 4425-4435.	6.7	113
62	Solution-Processed High-k Dielectric, ZrO <sub>2</sub> , and Integration in Thin-Film Transistors. Journal of Electronic Materials, 2012, 41, 895-898.	2.2	43
63	Charge transport and density of trap states in balanced high mobility ambipolar organic thin-film transistors. Organic Electronics, 2012, 13, 136-141.	2.6	40
64	Electrical characteristics of lateral organic bulk heterojunction device structures. Organic Electronics, 2012, 13, 1185-1191.	2.6	17
65	Thiophene- <i>b</i> -benzothiadiazole-thiophene (D-A-D) based polymers: effect of donor/acceptor moieties adjacent to D segment on photophysical and photovoltaic properties. Journal of Materials Chemistry, 2011, 21, 10532.	6.7	52
66	Synthesis, thin-film morphology, and comparative study of bulk and bilayer heterojunction organic photovoltaic devices using soluble diketopyrrolopyrrole molecules. Energy and Environmental Science, 2011, 4, 3617.	30.8	37
67	High mobility organic thin film transistor and efficient photovoltaic devices using versatile donor-acceptor polymer semiconductor by molecular design. Energy and Environmental Science, 2011, 4, 2288.	30.8	166
68	Analysis and modelling of lateral heterostructure field-effect bipolar transistors. Organic Electronics, 2011, 12, 1794-1799.	2.6	2
69	Charge carrier velocity distributions in field-effect transistors. Applied Physics Letters, 2011, 98, 092106.	3.3	5
70	Electrical characteristics of zinc oxide-organic semiconductor lateral heterostructure based hybrid field-effect bipolar transistors. Applied Physics Letters, 2011, 98, .	3.3	19
71	Velocity-field characteristics of polycrystalline pentacene field-effect transistors. Journal of Applied Physics, 2010, 107, .	2.5	9
72	A Low-Bandgap Diketopyrrolopyrrole-Benzothiadiazole-Based Copolymer for High-Mobility Ambipolar Organic Thin-Film Transistors. Advanced Materials, 2010, 22, 5409-5413.	21.0	397

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73	Solution-processed zinc-tin oxide thin-film transistors with low interfacial trap density and improved performance. Applied Physics Letters, 2010, 96, 243501.	3.3	115
74	Temperature dependent transient velocity and mobility studies in an organic field effect transistor. Journal of Applied Physics, 2010, 107, 113714.	2.5	17
75	Band transport and mobility edge in amorphous solution-processed zinc tin oxide thin-film transistors. Applied Physics Letters, 2010, 97, .	3.3	62
76	Electron transport in copper phthalocyanines. Journal of Applied Physics, 2010, 107, .	2.5	17
77	Nongeminate carrier recombination rates in organic solar cells. Applied Physics Letters, 2010, 97, .	3.3	12
78	Solution-Processed ZTO TFTs With Recessed Gate and Low Operating Voltage. IEEE Electron Device Letters, 2010, 31, 1410-1412.	3.9	31
79	Dynamic characterization of charge transport in organic and polymer transistors. Applied Physics A: Materials Science and Processing, 2009, 95, 153-158.	2.3	12
80	Zinc tin oxide thin film transistor sensor. Sensors and Actuators B: Chemical, 2009, 143, 50-55.	7.8	33
81	Synthesis, characterization and comparative study of thiophene-benzothiadiazole based donor-acceptor-donor (D-A-D) materials. Journal of Materials Chemistry, 2009, 19, 3228.	6.7	98
82	High-Mobility Organic Thin Film Transistors Based on Benzothiadiazole-Sandwiched Dihexylquaterthiophenes. Chemistry of Materials, 2008, 20, 3184-3190.	6.7	83
83	Drift mobility and the frequency response of diode connected organic transistors. Applied Physics Letters, 2008, 92, .	3.3	12
84	Dynamic characteristics and applications of organic and polymer transistors. , 2007, , .		0
85	Radio frequency rectifiers based on organic thin-film transistors. Applied Physics Letters, 2006, 88, 123502.	3.3	205
86	Organic and polymer transistors for electronics. Materials Today, 2006, 9, 24-30.	14.2	259
87	Organic complementary circuits using solution deposited active semiconductors. , 2006, , .		0
88	Direct measurement of carrier drift velocity and mobility in a polymer field-effect transistor. Applied Physics Letters, 2006, 89, 242104.	3.3	18
89	Nanoscale organic and polymeric field-effect transistors as chemical sensors. Analytical and Bioanalytical Chemistry, 2005, 384, 310-321.	3.7	110
90	Nanoscale chemical sensors based on conjugated polymer transistors. , 2004, 5522, 81.		3

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91	Photoluminescence characterization of the effects of rapid thermal annealing on AlGaAs/GaAs modulation-doped quantum wells. Journal of Electronic Materials, 1990, 19, 1333-1338.	2.2	3
92	Relationship between photoluminescence spectra and low-field electrical properties of modulation-doped AlGaAs/GaAs quantum wells. Journal of Applied Physics, 1990, 68, 4119-4126.	2.5	23